

Universal fast mode regime in wetting kinetics

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(Received 30 May 2022; accepted 2 October 2022; published 1 November 2022)

We present simulation results from a comprehensive molecular dynamics (MD) study of surface-directed spinodal decomposition (SDSD) in unstable symmetric binary mixtures at wetting surfaces. We consider long-ranged and short-ranged surface fields to investigate the early stage wetting kinetics. The attractive part of the long-ranged potential is of the form $V(z) \sim z^{-n}$, where z is the distance from the surface and n is the power-law exponent. We find that the wetting-layer thickness $R_1(t)$ at very early times exhibits a power-law growth with an exponent $\alpha = 1/(n+2)$. It then crosses over to a universal fast-mode regime with $\alpha = 3/2$. In contrast, for the short-ranged surface potential, a logarithmic behavior in $R_1(t)$ is observed at initial times. Remarkably, similar rapid growth is seen in this case too. We provide phenomenological arguments to understand these growth laws. Our MD results firmly establish the existence of universal fast-mode kinetics and settle the related controversy.

DOI: [10.1103/PhysRevE.106.L052801](https://doi.org/10.1103/PhysRevE.106.L052801)

Introduction. An immiscible binary ($A + B$) mixture in a homogeneous phase segregates into regions of A -rich and B -rich domains when quenched deep below the miscibility curve. This spontaneous decay of the unstable mixture is called *spinodal decomposition* (SD). This is an important example of coarsening or domain growth problems, which have received great attention in the literature [1–3]. Multi-component mixtures and their phase separation have immense scientific and technological applications in complex fluids such as polymer blends [4,5], emulsions [6,7], alloys and glasses [8,9], Ionic Liquids (ILs) [10], active materials for organic solar cells [11] and memristors [12], hardening of alloys [13], stabilization of proteins using ILs [14], and composite materials with enhanced mechanical strength and plasticity [15–18].

The morphology of domains formed due to phase segregation could be bicontinuous (interconnected) or droplets, depending upon the concentration ratio of the components in the mixture [1]. These coarsening domains follow power-law growth as $\ell(t) \sim t^\theta$, where the exponent θ defines the underlying physical mechanism for the transport of particles. The $\theta = 1/3$ for phase-separating binary solid alloys marks the diffusion as the primary mode of transportation in solids and is referred to as Lifshitz-Slyozov (LS) growth law [19]. For fluid mixtures, hydrodynamics comes into play at later times, and the resulting evolution exhibits a crossover to other exponent values, e.g., $\theta = 1$ followed by $\theta = 2/3$ in three-dimension (3D), owing to a faster advective transport of the particles [1,2,20–23].

Introducing a substrate (S), with a preferential attraction for one of the components (say, A) of this phase-segregating

mixture $A + B$, breaks the translational symmetry of the particle transportation in a direction perpendicular to the surface. It changes the kinetics and domain morphology at the surface [24,25]. If the system is now quenched below the spinodal curve, it spontaneously decomposes into A -rich and B -rich domains. Simultaneously, the system is wetted by the preferred component A . The wetting phenomenon of the surface in conjunction with the bulk phase separation is known as *surface-directed spinodal decomposition* (SDSD). The surface may evolve either in a *completely wet* (CW) or a *partially wet* (PW) morphology at equilibrium, depending upon the relative surface tensions between A , B , and S .

The SDSD phenomenon is effective in fabricating low cost, lightweight, and easy-to-process optoelectronic devices [26–28]. Phase-separated structures, including bicontinuous interconnected layers, droplets, pillars, and disks in organic thin films, ferroelectric transistors, organic photovoltaic devices (OPVs), etc., can be tailored to achieve distinct optical and electrical properties [11,29,30]. In particular, an OPV consists of an active layer featuring interconnected domain morphology for effective charge separation and layering near the substrate. This gives rise to an enhanced charge collection and improves the efficiency of optoelectronic devices [28,31–34]. Additionally, layering in SDSD can also enhance the physical, mechanical, and surface properties of polymer blends [4,32]. The layering, however, may also result in undesirable enrichment layers adversely affecting the mechanical and thermal properties of polymer blends [32,35]. Furthermore, SDSD provides methods for generating transient target morphologies in metallic or polymer mixtures (block copolymers) [36], etc., via chemically or morphologically patterned substrates or through the introduction of micro- or nano-sized filler particles [37–39]. These target morphologies show potential technological applications in bit-patterned media [40], nanowires [41], polarizers [42], ion conduction channels [43],

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nanolithography [44], and electrolytes in energy storage devices [45]. A few more recent SDSD applications include thin-film fabrication for oral drug delivery [46], microfluidic based liquid-liquid phase separation (water ILs) to recover on demand the IL-rich phase of interest [47], and food processing [48]. In the light of the above mentioned technological applications, it is compelling to understand and control the growth regimes of layered morphologies and coarsening bulk domains in SDSD.

Much scientific effort has been put into SDSD through analytical investigations [49–55], experimental studies [4,5,28,32,56–60], and computer simulations [2,24,35,37–39,61–76]. The Puri-Binder model (PB) [49] is the first successful theoretical model of SDSD for binary alloys and early-stage kinetics of polymer mixtures at the coarse-grained scale. This model consists of Cahn-Hilliard-Cook (CHC) equation for the phase separating mixture supplemented by two boundary conditions at the surface. Puri and Binder studied the kinetics of SDSD of critical mixtures (50%A – 50%B) for a short-ranged δ -function potential and formulated tools to characterize domain growth parallel and perpendicular to the wetting surface [77]. They found that the growth of the wetting-layer thickness $R_1(t)$ appeared to be logarithmic with time t .

Puri and Binder [65,66] considered the case when the surface exerts a long-ranged attractive force on the preferred component of the mixture. For surface interactions of the form $V(z) \sim z^{-n}$, they showed that the wetting layer at very early times exhibited power-law growth in the potential-dependent regime. The growth exponent was found to be strongly dependent on n . It then crosses over to a diffusive regime. Note that the above mentioned studies were based on the *diffusion-driven* model. However, for fluid mixtures, the hydrodynamics effects become relevant, and faster growth of the wetting layer is observed at late times [24,68,76]. Jaiswal *et al.* [67] carried out molecular dynamics simulation to study the kinetics of SDSD. They deduced the growth laws for the wetting-layer thickness $R_1 \sim t^\alpha$, with $\alpha \approx 1/3$ (diffusive regime) and $\alpha \approx 1$ (viscous hydrodynamic regime). The usual phase separation was observed for bulk domains.

In the present work, we perform comprehensive molecular dynamics (MD) simulation to investigate the effects of long-ranged power-law and short-ranged exponential surface potentials on the early-stage dynamics of SDSD. We primarily focus on the potential-dependent growth of the wetting layer for symmetric (critical) binary mixtures and its crossover to the diffusive regime via an intermediate *fast-mode kinetics*. The fast mode was observed experimentally for polymer blends as well as low-molecular-weight critical mixtures by Wiltzius, Cumming, and coworkers [58–60]. The existence of this fast mode has been controversial and disputed by several authors [74,78–80]. Further, a major gap remained in the literature, i.e., comprehensive atomistic simulations which would (a) confirm or refute the existence of a fast mode; and (b) if it exists, provide a reasonable theoretical explanation. Our present paper addresses precisely this gap, and settles the controversy. For the long-ranged interactions, we observe that the growth laws for $R_1(t)$ exhibit power-law behavior in various regimes. As the growth of the wetting layer unfolds, distinct and noteworthy crossovers are observed in the following

sequence: potential-dependent regime \rightarrow fast-mode regime \rightarrow diffusive regime \rightarrow hydrodynamic regime. In contrast, for the case with short-ranged wall potential, a logarithmic growth of the wetting layer is observed that again crosses over to a fast mode and subsequently to the well-established diffusive and hydrodynamic regimes.

Methodology. To study the surface-directed spinodal decomposition (SDSD), we carry out molecular dynamics (MD) simulations using LAMMPS [81] software package. We consider a binary mixture of A and B type particles in a box of volume $V = L \times L \times D$ with an equal number of A and B ($N_A = N_B = N/2$) particles. We apply periodic boundary conditions in x, y directions, and a wall is placed in the z direction at $z = 0$. The wall is impenetrable to either of the particles, and the simulation box constitutes a semi-infinite geometry.

The particle-wall interaction is modeled via an integrated Lennard-Jones (LJ) potential (u_w), given as

$$u_w(z) = \frac{2\pi\rho_N\sigma^3}{3} \left[\frac{2\epsilon_r}{15} \left(\frac{\sigma}{z'} \right)^9 + \delta_\alpha V(z') \right], \quad z' = z + \sigma/2, \quad (1)$$

with $V(z')$ representing the attractive potential and has been employed in two forms in the present study. These forms mimic the long-ranged and short-ranged surface interactions with the particles:

$$V(z') = \begin{cases} V_{\text{long}} = -\epsilon_a \left(\frac{\sigma}{z'} \right)^n, \\ V_{\text{short}} = -\epsilon_a \exp(-z'/z_0). \end{cases} \quad (2)$$

The parameters ϵ_r and ϵ_a set the energy scales for the wall-particle repulsion and attraction, respectively. σ is the LJ diameter, and ρ_N is the fluid density ($\rho_N = N/L^2D$). The attractive term in the potential in Eq. (1) is switched on or off using δ_α for “ α ” type of particles. Therefore, to have an A -rich wetting layer at $z = 0$, we set $\delta_A = 1$ and $\delta_B = 0$. Moreover, the variable z' in Eq. (1) is defined as $z' = z + \sigma/2$ so that the singularity in $u_w(z)$ occurs outside the simulation box at $z = -\sigma/2$. We place a confining surface at $z = D$ with $z' = D + \sigma/2 - z$. However, in this case, we set $\delta_A = \delta_B = 0$ so that both A and B particles are repelled. The particle-particle interaction and the other simulation details, including thermostat, integrator, etc., are provided in Sec. I of the Supplemental Material (SM) [82], which includes Refs. [22–24,65,83,84].

Results and Discussion. First, we present results from our molecular dynamics (MD) simulations for a long-ranged power-law potential defined in Eq. (2). The interaction potential parameters are $\epsilon_r = 0.6$ and $\epsilon_a = 0.5$ corresponding to a completely wet (CW) morphology in equilibrium [85]. The simulation box is $L^2 \times D$ with $L = D = 32$, i.e., the total number of particles is $N = 32768$. We present the evolution snapshots of the system in Fig. 1 for the power-law wall potential with an exponent $n = 3$. Noticeably, the bulk segregates into A -rich and B -rich phases with bicontinuous domain morphology. Moreover, the surface at $z = 0$ starts populating with A particles, whereas the B particles migrate towards the bulk. This leads to the formation of an A -rich layer at the surface with a B -rich depletion layer on top of it.

Further, the bulk domains as well as both the wetting and depletion layers grow with time (for instance, in Figs. 1(c) and

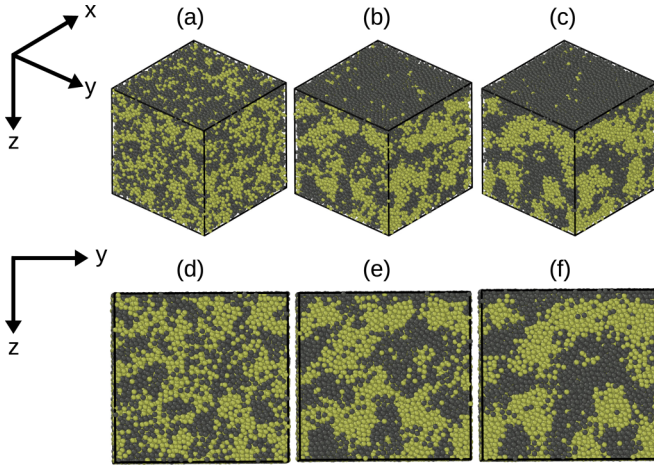


FIG. 1. Upper panel: Evolution snapshots for a binary Lennard-Jones mixture ($A + B$) undergoing surface-directed spinodal decomposition (SDSD) within a box of dimensions $L^2 \times D$, with $L = D = 32$. These snapshots correspond to $t = 40$ (a), $t = 200$ (b), and $t = 400$ (c). An impenetrable surface at $z = 0$ attracts A particles (marked in gray). The choice of interaction coefficients between the wall and particles, in Eq. (2), produces completely wet (CW) morphology at equilibrium. The system is quenched from a high temperature (corresponding to a homogeneous initial state) to $T = 1.0 < T_c$. The other simulation details are mentioned in the text and [82]. Lower panel: yz cross-sections of the snapshots shown in the upper panel at $x = L$.

(f) corresponding to $t = 400$, a thicker A -rich wetting layer is seen at the surface in comparison to Figs. 1(a) and (d) which correspond to $t = 40$). The transport of A -rich bulk tubes into the wetting layer is evident in Fig. 1(f). We stress that the tubes are not expected to stretch from top to bottom in Fig. 1(f) - rather, they connect bulk domains to the surface wetting layer. This flush of wettable tubes spreads along the surface and leads to the radial thickening of one end of the tube connected to the wetting layer (see Fig. S1 and movie SM1 [82]). The resultant wetting-layer growth is much faster than the diffusive dynamics and is attributed to the hydrodynamic effects [76,78,86,87]. We end our discussion on Fig. 1 by highlighting a similar observation (though, at a much earlier time) of hydrodynamic pumping of bulk tubes into the wetting layer (see Fig. S2 and movie SM2 [82]). This is the first numerical observation of what has been experimentally referred to as *fast-mode* kinetics [58,59]. Our MD results in this paper demonstrate the presence of a universal fast mode and it is the central result of this Letter.

The multilayered morphology shown in Fig. 1 results in the emergence of a wave-like structure known as the SDSD wave and can be corroborated from the depth profiles presented in Fig. 2. We employ the laterally-averaged order parameter for depth profiling of the morphology formed at the surface. The order parameter ψ is calculated from the local densities n_A and n_B as $\psi(x, y, z, t) = (n_A - n_B)/(n_A + n_B)$ and is then averaged over the xy plane in a fixed layer thickness $\Delta z = 0.5$ centered at different z values to produce the laterally-averaged order parameter $\psi_{av}(z, t)$. We finally average these profiles over 400 independent runs to improve the statistics. We plot $\psi_{av}(z, t)$ vs z in Fig. 2 for three different times

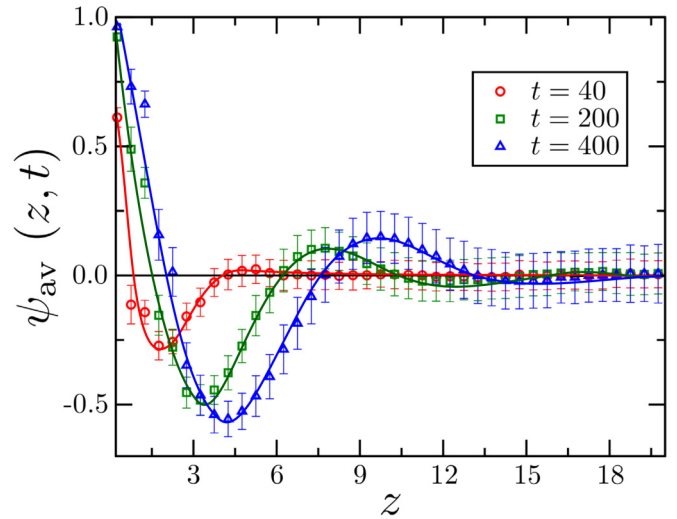


FIG. 2. Laterally-averaged order parameter profiles $\psi_{av}(z, t)$ vs z for the evolution shown in Fig. 1 at $t = 40$, 200, and 400. The solid lines through the data set are guides to the eye.

$t = 40$, 200, and 400 corresponding to potential-dependent, diffusive, and viscous hydrodynamic regimes respectively, as will be discussed shortly. The SDSD wave originates at the surface [where $\psi_{av}(z, t) \approx 1$] and vanishes into the bulk [where $\psi_{av}(z, t) \approx 0$]. Such depth profiles exhibit a structured oscillatory behavior at the surface and offer an experimental counterpart of depth profiling techniques [57].

We examine the evolution of the SDSD profile by computing the first zero crossing $R_1(t)$ from the laterally-averaged order parameter shown in Fig. 2. The quantity $R_1(t)$ characterizes the wetting-layer thickness, and its evolution with time t is shown in Fig. 3. We observe four distinct time regimes shaded in different colors: potential-dependent, fast-mode, diffusive, and viscous hydrodynamic regimes as time progresses. Each regime exhibits a power-law growth $R_1(t) \sim t^\alpha$ (where α denotes the growth exponent) and is punctuated by a sharp crossover. In our previous work on MD of SDSD [88], we established such a crossover from the universal diffusive regime ($\alpha = 1/3$) to the viscous hydrodynamic regime ($\alpha = 1$). However, we did not explore the early-time behavior of SDSD characterized by the potential-dependent regime and the fast mode.

The primary objectives of this work are to obtain the growth laws for the early-time kinetics. The growth exponent for the wetting-layer thickness at early times is $\alpha \approx 1/5$ for the power-law surface potential with $n = 3$. This is consistent with the phenomenological theory of SDSD [49] discussed in the Supplemental Material, Sec. II [82]. As time evolves, the potential-dependent growth crosses over to a very rapid regime with an exponent $\alpha \approx 3/2$. The short-lived accelerated growth in $t \in (60, 100)$ (see Fig. 3) is the first numerical observation of the *fast-mode kinetics* observed in experiments by Wiltzius, Cumming, and others [58–60].

How do we comprehend the fast-mode kinetics seen for the growth in the wetting-layer thickness? The earlier studies reported in the literature were not conclusive: the primary reason was that the regime was very short-lived and was suggested to be transient [58,75,76]. To this end, we

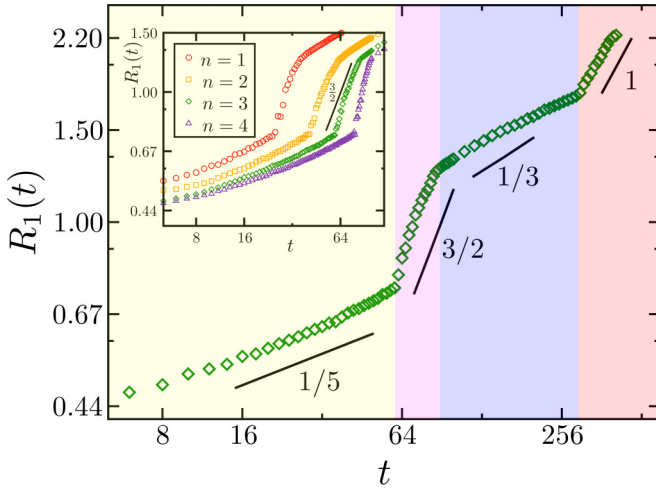


FIG. 3. The time dependence of $R_1(t)$ on a log-log scale for the CW morphology. The results are presented for the power-law surface potential $-\epsilon_a/z^n$. Main figure: the wetting-layer growth when the surface potential is specified by $n = 3$, corresponding to van der Waals' interaction. The straight lines having slopes $1/5$, $1/3$, and 1 correspond to the potential-dependent, diffusive, and hydrodynamic regimes, respectively. Inset: $R_1(t)$ vs t for the potential specified by $n = 1, 2, 3$, and 4 . The solid line with slope $3/2$ suggests the fast mode observed by Wiltzius and Cumming [58].

perform our simulations for different values of n (as defined in $V(z) \sim z^{-n}$), and also examine the effect of varying the range of the surface potential. We show these results in the inset of Fig. 3 where we plot $R_1(t)$ vs t for $n = 1, 2, 3$, and 4 ($n = \infty$ will correspond to a δ -function potential). Conspicuously, the crossover from the potential-dependent regime to the universal fast-mode regime is seen for all the values of n . However, the regime is indeed short-lived, following the experiments [58,75,76]. It is worthwhile to mention here that the growth exponent for $R_1(t)$ is nearly the same (i.e., $R_1(t) \sim t^\alpha$ with $\alpha \approx 3/2$) for all n values in the fast-mode regime. Therefore, we conclude that the fast-mode kinetics also follows a universal power-law growth with an exponent $3/2$, in addition to the diffusive ($\alpha \approx 1/3$) and viscous hydrodynamic ($\alpha \approx 1$) regimes. In contrast, we find different power-law behaviors for early time (before the fast mode triggers) as we change n . Consequently, we label this as the *potential-dependent regime*. We study this regime in the Supplemental Material (SM), Sec. V [82].

We now recall Tanaka's argument [76,78,87] for the observed large exponent $\alpha \approx 3/2$. Due to the pressure gradient between the interconnected bicontinuous tubes of the wetting component and the surface, a flux estimated as $J \sim (\gamma/\eta)a^2$ is developed. Here, γ , η , and a (see SM Fig. S2) denote surface tension, viscosity, and tube radius, respectively. In the case of strong wettability, the tubes are hydrodynamically flushed towards the surface, and the coating dynamics is observed via lateral spreading of a droplet near the surface. The onset of the fast mode occurs when the tubes get connected with the surface droplets. This regime ends when the surface droplets merge to form a complete coating or wetting layer. The radius of the droplet $L_s(t)$ (see SM Fig. S2) in 3D grows as $dL_s^2/dt \sim (\gamma/\eta)a^2$. Now, applying Siggia's law

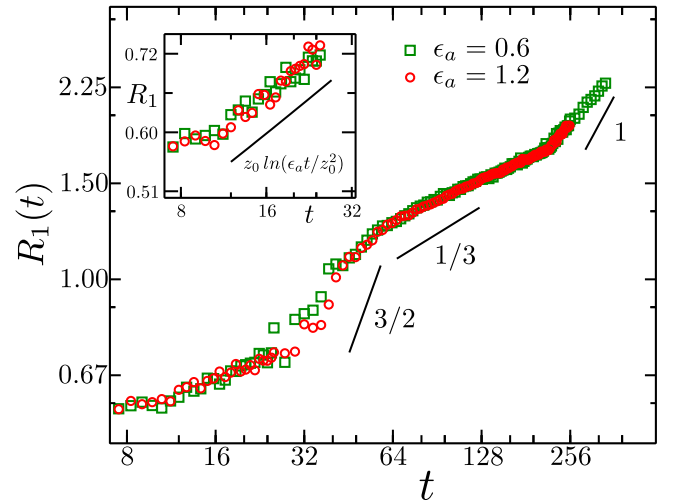


FIG. 4. The wetting-layer thickness $R_1(t)$ with time t on a log-log scale for a short-ranged surface field $V(z) = -\epsilon_a \exp(-z/z_0)$. The parameter z_0 is set to 0.5 , and the field strengths are $\epsilon_a = 0.6$ (green square) and $\epsilon_a = 1.2$ (red circle). It is significant to see the fast mode in this case too. At late times, the plot exhibits the diffusive and hydrodynamic regimes, in succession. Inset: Early time behavior of $R_1(t)$ illustrating a logarithmic growth. The straight line has a slope $z_0 \ln(\epsilon_a t/z_0^2)$.

$a(t) \sim (\gamma/\eta)t$ the growth of the wetting-layer thickness is obtained as $R_1(t) \sim L_s(t) \sim [(\gamma/\eta)t]^{3/2}$. This agrees with the earlier experimental observations [58–60] and our present MD simulations. The scaling behavior of the crossover time (t_1) from the potential-dependent regime [$R_1 \sim (\epsilon_a t)^{1/(n+2)}$, see SM] to the fast mode regime can be estimated as

$$t_1 \sim \epsilon_a^{2/(3n+4)} \left(\frac{\eta}{\gamma} \right)^{(3n+6)/(3n+4)}. \quad (3)$$

The crossover from the fast mode to diffusive growth [$R_1 \sim (\gamma t)^{1/3}$, see SM] occurs at $t_2 \sim \eta^{9/7}/\gamma$.

Further, as n increases (see inset of Fig. 3), the decrease in the range of $V(z)$ results in a reduced surface effect on the wetting-layer growth. This increases the crossover time to the fast mode. Nevertheless, the values of $R_1(t) \sim 0.75\sigma$ at the onset of fast mode and $R_1(t) \sim 1.25\sigma$ at the onset of diffusion-driven growth do not change with varying n and remain almost fixed. We further make an important observation for the accelerated growth of $R_1(t) \sim 0.75\sigma$ to $R_1(t) \sim 1.25\sigma$ implying the completion of first wetting-layer structure with an average thickness $\sim \sigma$. This completion of the first wetting layer (*coating dynamics*) is assisted by the domains near the surface via the hydrodynamic pumping mechanism (see Fig. S2 and movie SM2 [82]) [78].

We also simulated the present system with an exponential wall potential $V(z) = -\epsilon_a \exp(-z/z_0)$ [see Eq. (2)] for the surface at $z = 0$. Figure 4 shows the evolution of $R_1(t)$ for two different surface field strengths. The early-time regime is short but our MD data is consistent with logarithmic growth $R_1(t) \sim z_0 \ln(\epsilon_a t/z_0^2)$, as predicted earlier [24]. This is highlighted in the inset of Fig. 4 on a log-linear scale. The main figure plots R_1 vs t on a log-log scale, which shows the late-time behavior analogous to the long-ranged case. The wetting kinetics

exhibits the usual power-law growth ($R_1(t) \sim t^\alpha$). The universal diffusive regime ($\alpha = 1/3$) is preceded by a transient faster growth ($\alpha \approx 3/2$) associated with the fast-mode kinetics. We conclude that the fast-mode kinetics is *universal* in nature. Additionally, at very late times, we observe the well-known viscous hydrodynamic regime with an exponent $\alpha \approx 1$. To the best of our understanding, the results (for both short-ranged and long-ranged interactions) presented in this work are the first atomistic simulations which access all the growth regimes of wetting kinetics.

Final remarks. In conclusion, we have performed extensive molecular dynamics (MD) simulations of surface-directed spinodal decomposition (SDSD) of symmetric fluid mixtures at a wetting surface. The symmetry-breaking surface potentials studied here are long-ranged (power-law) and short-ranged (exponential) potentials. We present results for various growth regimes of wetting-layer thickness $R_1(t)$ extracted from the SDSD depth profiles. Each segment of the time dependence of $R_1(t)$ reflects a different transport mechanism inaction responsible for different growth laws. The prime focus of this work is to settle any controversy regarding the existence of a universal fast-mode. In our simulations, this is unambiguously seen as a crossover regime between the potential-dependent growth and the universal diffusive dynamics. Our evolution snapshots and movies show these fast mode results from the rapid growth of droplets preced-

ing the formation of the wetting layer. This is enabled by the emergence of bulk fluid tubes, which rapidly drain material into the surface droplets. The corresponding growth exponent is $\approx 3/2$. This is consistent with the experimental works on binary polymer blends, a fluid mixture of guaiacol and glycerol-water, etc., by Wiltzius, Cumming, and others [58–60] and theoretical predictions by Tanaka [78,86,87]. Regardless of the surface-field form, its range, and strength, we find a fast mode with the universal growth exponent $\approx 3/2$. For the long-ranged surface potential, $V(z) \sim z^{-n}$, $R_1(t)$ displays a power-law dependence with $R_1(t) \sim t^{1/(n+2)}$ at very early times, supporting the phenomenological theory [65]. Finally, in the case of short-ranged potential, $R_1(t)$ shows a logarithmic growth followed by fast-mode, diffusive, and hydrodynamic regime. To the best of our understanding, the results (for both short-ranged and long-ranged interactions) presented in this work are the first atomistic simulations that access all the growth regimes of wetting kinetics.

Acknowledgments. P.K.J. is thankful to IIT Jodhpur for a Seed Grant (I/SEED/PKJ/20220016). M.P. acknowledges funding from Department of Science and Technology (DST), India, through a SERB-ECR Grant No. ECR/2017/003091. S.P. is grateful to the Department of Science and Technology, India for support via a J.C. Bose fellowship.

All authors declare they have no competing interests.

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